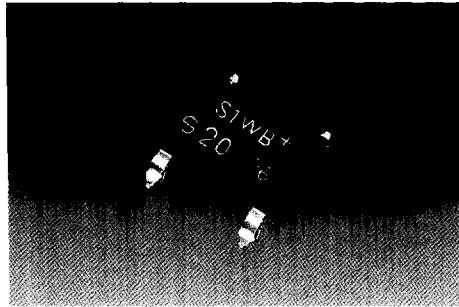


プリッジ型 Bridge Diode

一般整流ダイオード

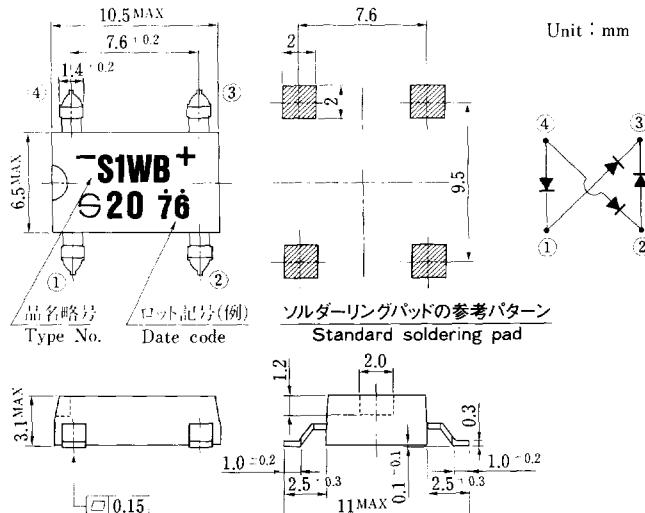
Rectifier Diode

S1WB(A)□
S1WB(A)□B
600V 1A



■ 外形寸法図 OUTLINE DIMENSIONS

Case : WB Type



■ 定格表 RATINGS

絶対最大定格 Absolute Maximum Ratings

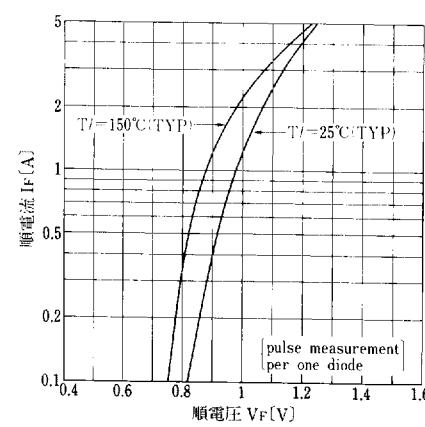
| 項目 Item | 記号 Symbol | 条件 Conditions | 品名 Type No. | S1WB(A)□ | | | S1WB(A)□B | | | 単位 Unit |
|---|------------------|---|----------------|----------|-----|-----|-----------|---------|-----|------------|
| | | | | 10 | 20 | 40 | 60 | 40 | 60 | |
| 保存温度 Storage Temperature | Tstg | | | | | | | -40~150 | | °C |
| 接合部温度 Operating Junction Temperature | Tj | | | | | | | 150 | | °C |
| せん頭逆電圧 Maximum Reverse Voltage | V _{RM} | | | 100 | 200 | 400 | 600 | 400 | 600 | V |
| 出力電流 Average Rectified Forward Current | I _O | 50Hz 正弦波, 抵抗負荷, T _a =25°C 50Hz sine wave, R-load, T _a =25°C | | | | | | 1 | | A |
| せん頭サージ順電流 Peak Surge Forward Current | I _{FSM} | 50Hz 正弦波, 非繰り返し 1 サイクルせん頭値, T _j =25°C 50Hz sine wave, Non-repetitive 1 cycle peak value, T _j =25°C | | | | 30 | | 50 | | A |

電気的・熱的特性 Electrical Characteristics (T_l=25°C)

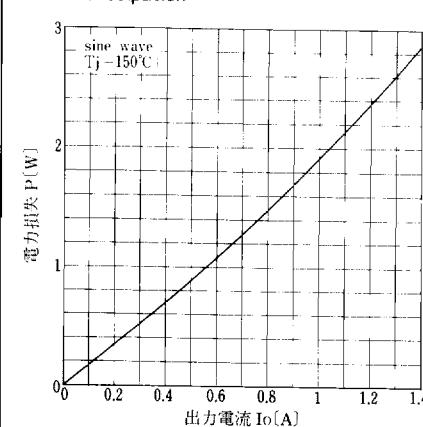
| | | | | | |
|---------------------------|-----------------|---|--|--------|------|
| 順電圧 Forward Voltage | V _F | I _F =0.5A, パルス測定, 1 素子当りの規格値 I _F =0.5A, Pulse measurement, Rating of per diode | | MAX 1 | V |
| 逆電流 Reverse Current | I _R | V _R =V _{RM} , パルス測定, 1 素子当りの規格値 V _R =V _{RM} , Pulse measurement, Rating of per diode | | MAX 10 | μA |
| 熱抵抗 Thermal Resistance | θ _{jl} | 接合部・リード間 Junction to lead | | MAX 10 | °C/W |
| | θ _{ja} | 接合部・周囲間 Junction to ambient | | MAX 65 | |

■ 特性図 CHARACTERISTIC DIAGRAMS

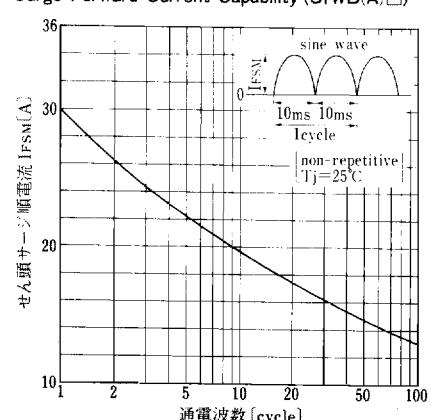
順方向特性
Forward Voltage



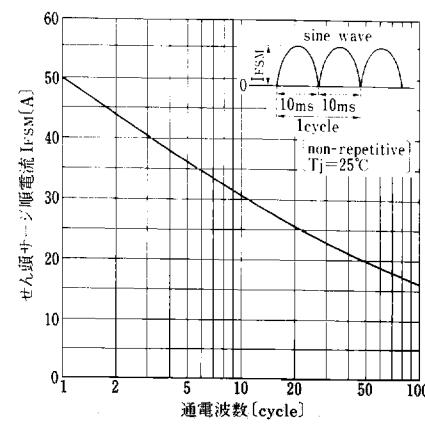
電力損失曲線
Power Dissipation



せん頭サージ順電流耐量 (S1WB(A)□用)
Surge Forward Current Capability (S1WB(A)□)



せん頭サージ順電流耐量 (S1WB(A)□B用)
Surge Forward Current Capability (S1WB(A)□B)



ディレーティングカーブ Ta-Io
Derating Curve Ta-Io

